## NSN 5961-01-171-1973

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-171-1973 **Inclosure Material:** Metal **Mounting Facility Quantity: Mounting Method:** Threaded stud **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 125.0 reverse voltage, peak **Capacitance Rating In Picofarads:** 90.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air Shelf Life: N/a **Unit Of Measure:** Demilitarization:

No Fiig: A110a0